

## 8 A Snubberless™ Triac

#### Datasheet - production data

#### **Features**

- High static and dynamic commutation
- Package is RoHS (2002/95/EC) compliant
- High surge current
- ECOPACK<sup>®</sup>2 compliant component
- Complies with UL standards (File ref: E81734)

### **Applications**

- General purpose AC switching
- Motor control circuits in power tools
- Home appliances
- Lighting

### **Description**

The T830-8FP Triac can be used for the on/off function in general purpose AC switching where high commutation capability is required.

Provides insulation rated at 1500 V rms.

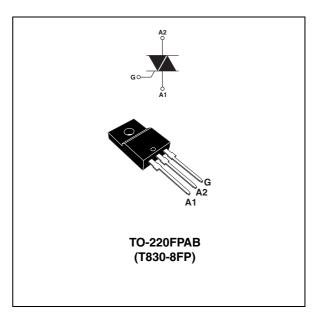


Table 1. Device summary

| Symbol              | Value | Unit |  |  |
|---------------------|-------|------|--|--|
| I <sub>T(rms)</sub> | 8     | Α    |  |  |
| $V_{DRM}, V_{RRM}$  | 800   | V    |  |  |
| $V_{DSM}, V_{RSM}$  | 900   | V    |  |  |
| I <sub>GT</sub>     | 30    | mA   |  |  |

Characteristics T830-8FP

## 1 Characteristics

Table 2. Absolute ratings (limiting values)

| Symbol                                 | Parameter  |                        |                         | Value                          | Unit             |
|--|--|------------------------|-------------------------|--------------------------------|------------------|
| I <sub>T(rms)</sub>                    | On-state rms current (full sine wave   | )                      | T <sub>c</sub> = 95 °C  | 8                              | Α                |
| l                                      | Non repetitive surge peak on-state   | F = 50 Hz              | t = 20 ms               | 80                             | Α                |
| I <sub>TSM</sub>                       | current (full cycle, T <sub>j</sub> initial = 25 °C)   | F = 60 Hz              | t = 16.7 ms             | 84                             | ^                |
| l <sup>2</sup> t                       | I <sup>2</sup> t Value for fusing  | $t_p = 10 \text{ ms}$  |                         | 42                             | A <sup>2</sup> s |
| dI/dt                                  | Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , $t_r \le 100 \text{ ns}$ | F = 120 Hz             | T <sub>j</sub> = 125 °C | 100                            | A/μs             |
| V <sub>DSM</sub> ,<br>V <sub>RSM</sub> | Non repetitive surge peak on-state voltage   | t <sub>p</sub> = 10 ms | T <sub>j</sub> = 25 °C  | 900                            | ٧                |
| I <sub>GM</sub>                        | Peak gate current  | t <sub>p</sub> = 20 μs | T <sub>j</sub> = 125 °C | 4                              | Α                |
| P <sub>G(AV)</sub>                     | Average gate power dissipation $T_j = 125$ °C  |                        |                         | 1                              | W                |
| T <sub>stg</sub>                       | Storage junction temperature range Operating junction temperature range                      |                        |                         | - 40 to + 150<br>- 40 to + 125 | °C               |
| TL                                     | Lead temperature for soldering during 10 s (at 4 mm from case)                               |                        |                         | 260                            | °C               |
| V <sub>ins</sub>                       | Insulation rms voltage, 1 minute   |                        |                         | 1500                           | V                |

Table 3. Electrical characteristics ( $T_j = 25$  °C, unless otherwise specified)

| Symbol                         | Test conditions Quadrant  |                         |        | Value | Unit |
|--------------------------------|---|-------------------------|--------|-------|------|
| I <sub>GT</sub> <sup>(1)</sup> | $V_{\rm D} = 12 \text{ V}, R_{\rm I} = 30 \Omega$                               | 1 - 11 - 111            | Max.   | 30    | mA   |
| V <sub>GT</sub>                | VD = 12 V, NL = 30 S2   | 1 - 11 - 111            | iviax. | 1.3   | V    |
| $V_{GD}$                       | $V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega, T_j = 125 \text{ °C}$   I - II - III |                         | Min.   | 0.2   | V    |
| I <sub>H</sub> <sup>(2)</sup>  | I <sub>T</sub> = 250 mA   |                         | Max.   | 50    | mA   |
| ΙL                             | I <sub>G</sub> = 1.2 I <sub>GT</sub>  | 1 - 11 - 111            | Max.   | 60    | mA   |
| dV/dt                          | $V_D = 67\%V_{DRM}$ , gate open $T_j =$   |                         | Min.   | 2500  | V/µs |
| (dl/dt)c                       | Without snubber   | T <sub>j</sub> = 125 °C | Min.   | 10.0  | A/ms |

<sup>1.</sup> Minimum  $I_{GT}$  is guaranteed at 5% of  $I_{GT}$  max.

<sup>2.</sup> For both polarities of A2 referenced to A1.

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Table 4. Static characteristics

| Symbol                                  | Test conditions                                   |                         |        | Value | Unit |
|---|---|-------------------------|--------|-------|------|
| V <sub>T</sub> <sup>(1)</sup>           | $I_{TM} = 11 \text{ A}, t_p = 380 \ \mu \text{s}$ | T <sub>j</sub> = 25 °C  | Max.   | 1.55  | V    |
| V <sub>t0</sub> (1)                     | Threshold voltage                                 | T <sub>j</sub> = 125 °C | Max.   | 0.85  | V    |
| R <sub>d</sub> <sup>(1)</sup>           | Dynamic resistance                                | T <sub>j</sub> = 125 °C | Max.   | 40    | mΩ   |
| $I_{DRM}$ $I_{RRM}$ $V_{DRM} = V_{RRM}$ | V -V  | T <sub>j</sub> = 25 °C  | Max.   | 5     | μΑ   |
|   | VDRM = VRRM                                       | T <sub>j</sub> = 125 °C | iviax. | 1     | mA   |

<sup>1.</sup> For both polarities of A2 referenced to A1.

Table 5. Thermal resistance

| Symbol               | Parameter             | Value | Unit |
|----------------------|-----------------------|-------|------|
| R <sub>th(j-c)</sub> | Junction to case (AC) | 3.5   | °C/W |
| R <sub>th(j-a)</sub> | Junction to ambient   | 60    | °C/W |

Figure 1. Maximum power dissipation versus Figure 2. On-state rms current versus case rms on-state current temperature

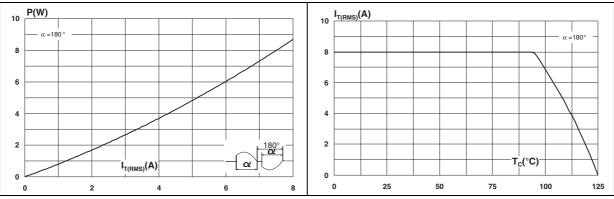
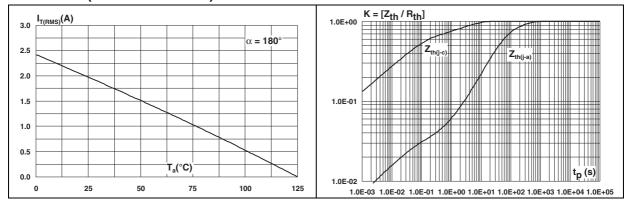


Figure 3. On-state rms current versus ambient temperature (free air convection)

Figure 4. Relative variation of thermal impedance versus pulse duration



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Figure 5. Relative variation of gate trigger current versus junction temperature (typical values)

Figure 6. Relative variation of gate trigger voltage versus junction temperature (typical values)

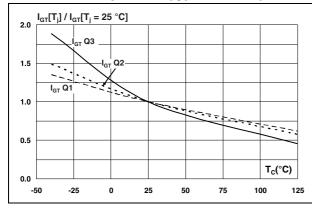
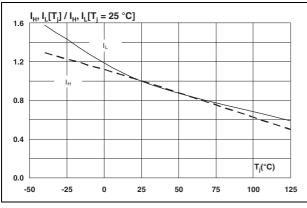


Figure 7. Relative variation of holding and latching current versus junction temperature (typical values)

Figure 8. Surge peak on-state current versus number of cycles



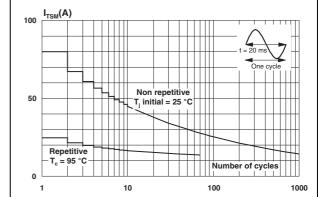
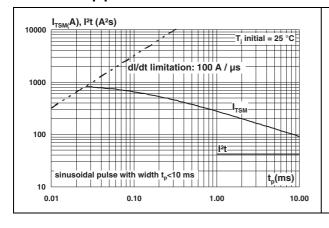
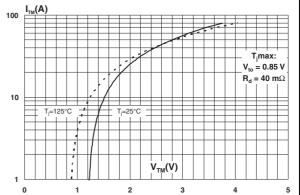


Figure 9. Non repetitive surge peak on-state Figure 10. current and corresponding value of I<sup>2</sup>T

Figure 10. On-state characteristics (maximum values)





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Figure 11. Relative variation of critical rate of Figure 12. Relative variation of static dV/dt decrease of main current versus immunity versus junction junction temperature temperature (typical values)

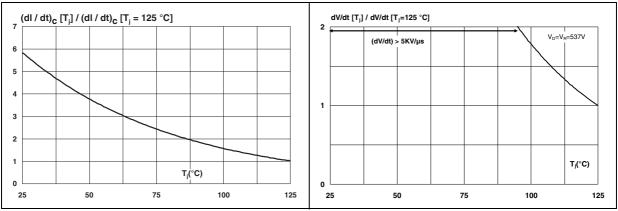
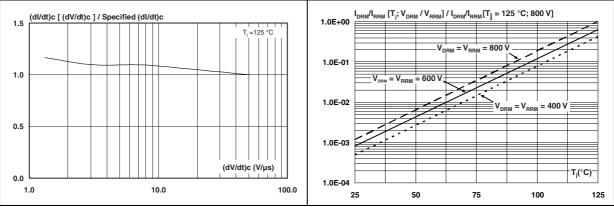


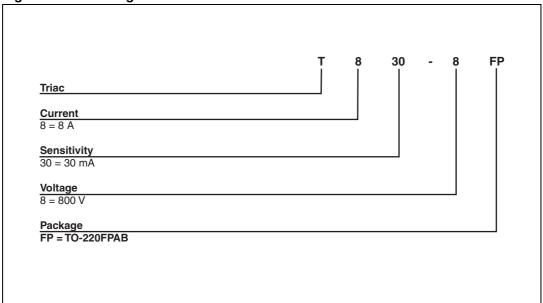
Figure 13. Relative variation of critical rate of Figure 14. decrease of main current versus reapplied dV/dt (typical values)

Figure 14. Relative variation of leakage current versus junction temperature



# 2 Ordering information scheme

Figure 15. Ordering information scheme



T830-8FP Package information

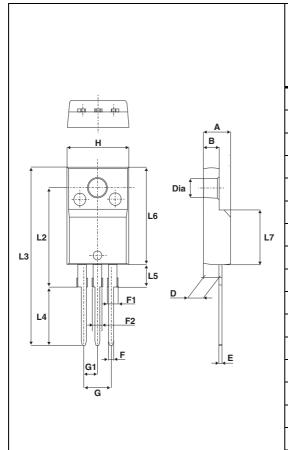
## 3 Package information

Epoxy meets UL94, V0

Recommended torque: 0.4 to 0.6 N⋅m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK $^{\circledR}$  packages, depending on their level of environmental compliance. ECOPACK $^{\circledR}$  specifications, grade definitions and product status are available at: www.st.com. ECOPACK $^{\circledR}$  is an ST trademark.

Table 6. TO-220FPAB Dimensions



|      | Dimensions  |      |             |       |
|------|-------------|------|-------------|-------|
| Ref. | Millimeters |      | Inches      |       |
|      | Min.        | Max. | Min.        | Max.  |
| Α    | 4.4         | 4.6  | 0.173       | 0.181 |
| В    | 2.5         | 2.7  | 0.098       | 0.106 |
| D    | 2.5         | 2.75 | 0.098       | 0.108 |
| Е    | 0.45        | 0.70 | 0.018       | 0.027 |
| F    | 0.75        | 1    | 0.030       | 0.039 |
| F1   | 1.15        | 1.70 | 0.045       | 0.067 |
| F2   | 1.15        | 1.70 | 0.045       | 0.067 |
| G    | 4.95        | 5.20 | 0.195       | 0.205 |
| G1   | 2.4         | 2.7  | 0.094       | 0.106 |
| Η    | 10          | 10.4 | 0.393 0.409 |       |
| L2   | 16 Typ.     |      | 0.63 Typ.   |       |
| L3   | 28.6        | 30.6 | 1.126 1.20  |       |
| L4   | 9.8         | 10.6 | 0.386       | 0.417 |
| L5   | 2.9         | 3.6  | 0.114       | 0.142 |
| L6   | 15.9        | 16.4 | 0.626       | 0.646 |
| L7   | 9.00        | 9.30 | 0.354       | 0.366 |
| Dia. | 3.00        | 3.20 | 0.118       | 0.126 |

Ordering information T830-8FP

# 4 Ordering information

 Table 7.
 Ordering information

| Order code | Marking  | Package    | Weight | Base qty | Delivery mode |
|------------|----------|------------|--------|----------|---------------|
| T830-8FP   | T830-8FP | TO-220FPAB | 2.0 g  | 50       | Tube          |

# 5 Revision history

Table 8. Document revision history

| Date        | Revision | Changes          |
|-------------|----------|------------------|
| 24-Sep-2012 | 1        | Initial release. |

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